

INFORMATION DISCLOSURE CITATION

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Ming-i M. Lin et al.

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U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
lll	6,560,746	5/2003	Morsberger	714	781	8-25-99
lll	6,223,320	4/2001	Dubey et al.	714	757	2-10-98
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FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

lll	Albertengo et al., PARALLEL CRC GENERATION, 10/1990 IEEE, pages 63-71.
lll	Pei et al., HIGH-SPEED PARALLEL CRC CIRCUITS IN VLSI, Vol. 40, No. 4, April 1992 IEEE, pages 653-656.

EXAMINER

lll

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